

PNP SILICON PLANAR MEDIUM POWER TRANSISTORS IN SOT89

Features

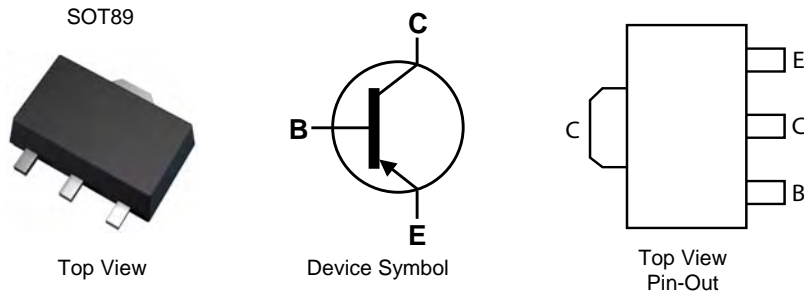
- $I_C = -1A$ Continuous Collector Current
- Low Saturation Voltage $V_{CE(sat)} < -500mV @ -0.5A$
- Gain groups 10 and 16
- Epitaxial Planar Die Construction
- Complementary NPN types: BCX54, 55, and 56
- **Lead-Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free. "Green" Devices (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound (Note 2)
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.072 grams (Approximate)

Applications

- Medium Power Switching or Amplification Applications
- AF driver and output stages

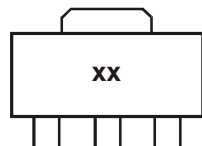


Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCX51TA	AA	7	12	1,000
BCX5110TA	AC	7	12	1,000
BCX5116TA	AD	7	12	1,000
BCX52TA	AE	7	12	1,000
BCX5210TA	AG	7	12	1,000
BCX5216TA	AM	7	12	1,000
BCX53TA	AH	7	12	1,000
BCX5310TA	AK	7	12	1,000
BCX5316TA	AL	7	12	1,000
BCX5316TC	AL	13	12	4,000
BCX5316-13R	AL	13	12	4,000

- Notes:
1. No purposefully added lead.
 2. Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>
 3. For packaging details, go to our website <http://www.diodes.com>

Marking Information



xx = Product Type Marking Code, as follows:

- | | | |
|--------------|--------------|--------------|
| BCX51 = AA | BCX52 = AE | BCX53 = AH |
| BCX5110 = AC | BCX5210 = AG | BCX5310 = AK |
| BCX5116 = AD | BCX5316 = AM | BCX5316 = AL |

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	BCX51	BCX52	BCX53	Unit
Collector-Base Voltage	V_{CBO}	-45	-60	-100	V
Collector-Emitter Voltage	V_{CEO}	-45	-60	-80	V
Emitter-Base Voltage	V_{EBO}		-5		V
Continuous Collector Current	I_C		-1		A
Peak Pulse Collector Current	I_{CM}		-1.5		
Continuous Base Current	I_B		-100		mA
Peak Pulse Base Current	I_{BM}		-200		

Thermal Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P_D	1	W
Thermal Resistance, Junction to Ambient (Note 4)	$R_{\theta JA}$	124	$^\circ\text{C/W}$
Thermal Resistance, Junction to Leads (Note 5)	$R_{\theta JL}$	10.0	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	$^\circ\text{C}$

- Notes:
4. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 5. Thermal resistance from junction to solder-point (on the exposed collector pad).

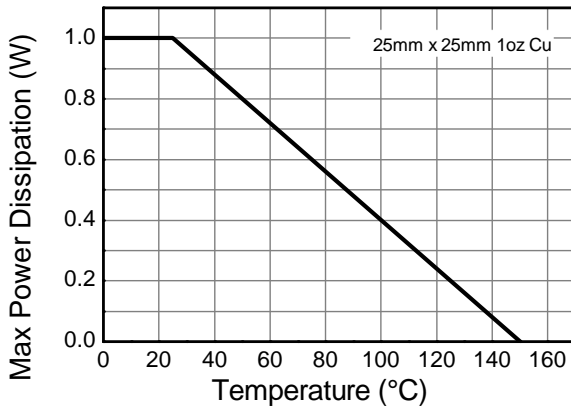
Thermal Characteristics



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BCX51	BV_{CBO}	-45	-	-	V	$I_C = -100\mu\text{A}$
	BCX52		-60				
	BCX53		-100				
Collector-Emitter Breakdown Voltage (Note 6)	BCX51	BV_{CEO}	-45	-	-	V	$I_C = -10\text{mA}$
	BCX52		-60				
	BCX53		-80				
Emitter-Base Breakdown Voltage		BV_{EBO}	-5	-	-	V	$I_E = -10\mu\text{A}$
Collector Cut-off Current		I_{CBO}	-	-	-0.1 -20	μA	$V_{CB} = -30\text{V}$ $V_{CB} = -30\text{V}, T_A = 150^\circ\text{C}$
Emitter Cut-off Current		I_{EBO}	-	-	-20	nA	$V_{EB} = -4\text{V}$
Static Forward Current Transfer Ratio (Note 6)	All versions	h_{FE}	25	-	-		$I_C = -5\text{mA}, V_{CE} = -2\text{V}$ $I_C = -150\text{mA}, V_{CE} = -2\text{V}$ $I_C = -500\text{mA}, V_{CE} = -2\text{V}$
			40	-	250		
	25		-	-			
	10 gain grp		63	-	160		
	16 gain grp	100	-	250		$I_C = -150\text{mA}, V_{CE} = -2\text{V}$	
Collector-Emitter Saturation Voltage (Note 6)		$V_{CE(sat)}$	-	-	-0.5	V	$I_C = -500\text{mA}, I_B = -50\text{mA}$
Base-Emitter Turn-On Voltage (Note 6)		$V_{BE(on)}$	-	-	-1.0	V	$I_C = -500\text{mA}, V_{CE} = -2\text{V}$
Transition Frequency		f_r	150	-	-	MHz	$I_C = -50\text{mA}, V_{CE} = -10\text{V}$ $f = 100\text{MHz}$
Output Capacitance		C_{obo}	-	-	25	pF	$V_{CB} = -10\text{V}, f = 1\text{MHz}$

Notes: 6. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

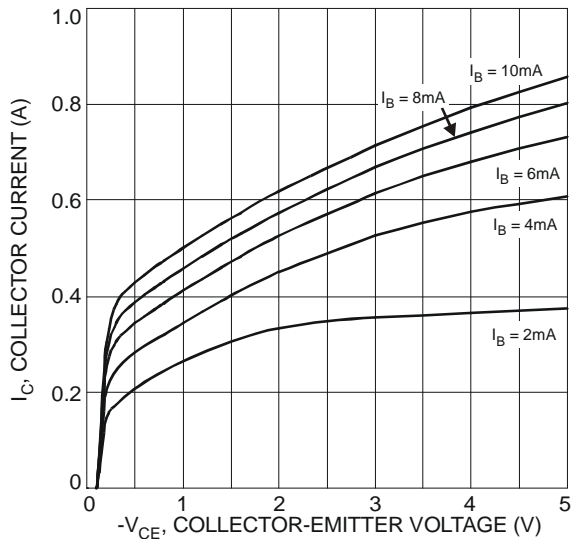


Fig. 1 Typical Collector Current vs. Collector-Emitter Voltage

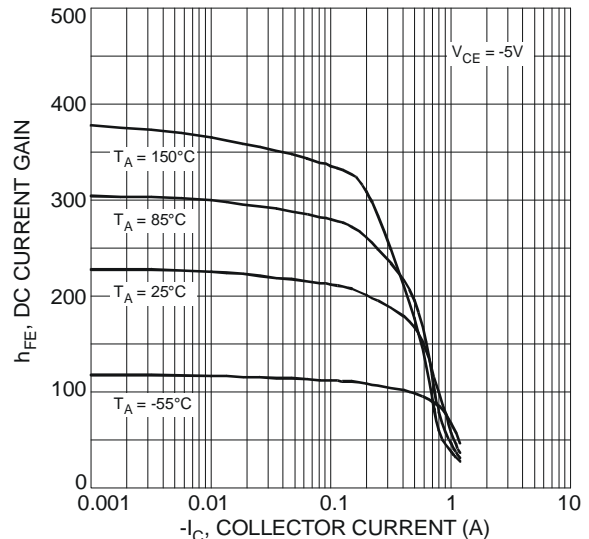


Fig. 2 Typical DC Current Gain vs. Collector Current



Fig 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current



Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current



Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

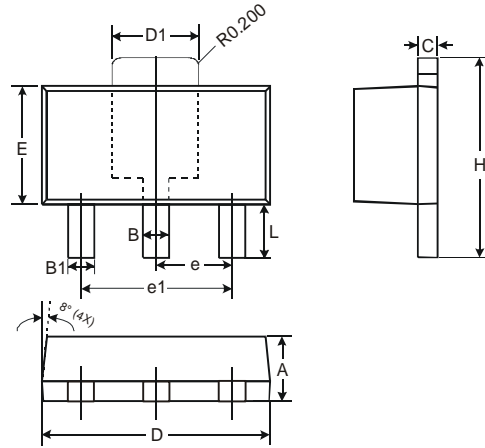


Fig. 6 Typical Gain-Bandwidth Product vs. Collector Current



Fig. 7 Typical Capacitance Characteristics

Package Outline Dimensions



SOT89		
Dim	Min	Max
A	1.40	1.60
B	0.44	0.62
B1	0.35	0.54
C	0.35	0.43
D	4.40	4.60
D1	1.52	1.83
E	2.29	2.60
e	1.50 Typ	
e1	3.00 Typ	
H	3.94	4.25
L	0.89	1.20
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
X	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2011, Diodes Incorporated

www.diodes.com



Стандарт Электрон Связь

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
помещение 100-Н Офис 331